

# Anisotropic spin transport in graphene interfaced with topological insulators

**Aron W. Cummings**

David Soriano, Kenan Song, Roberto Robles, Pablo Ordejón, Stephan Roche

Catalan Institute of Nanoscience and Nanotechnology (ICN2), CSIC and BIST, Campus UAB, Bellaterra, 08193 Barcelona, Spain

[aron.cummings@icn2.cat](mailto:aron.cummings@icn2.cat)

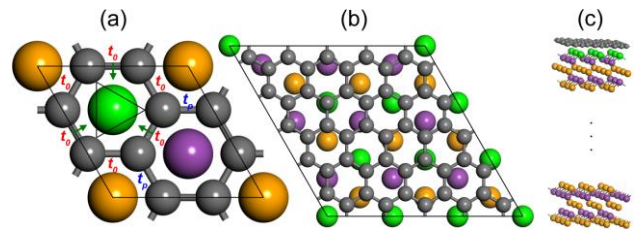
Owing to its small spin-orbit coupling (SOC), graphene has proven to be an efficient carrier of spin [1], making it promising for spintronics applications. However, a small SOC prevents the active manipulation or generation of spin currents. Recent work has thus focused on interfacing graphene with high-SOC materials such as transition metal dichalcogenides (TMDCs) or topological insulators (TIs), in the hope of inducing strong SOC in graphene while maintaining its superior charge transport properties [2-5].

In this talk, I will present our group's recent efforts to describe the nature of SOC and spin transport induced in graphene by proximity to TIs. We find that spin transport in these systems is distinguished by giant spin lifetime anisotropy, with spins oriented in the graphene plane relaxing much faster than spins pointing out of the plane [6]. This anisotropy arises from the specific nature of the SOC induced in the graphene layer, which depends crucially on the symmetry of the graphene/TI interface. In addition to serving as a probe of SOC induced in graphene, giant spin lifetime anisotropy may also prove useful for spintronics, for example serving as an orientation-dependent spin filter.

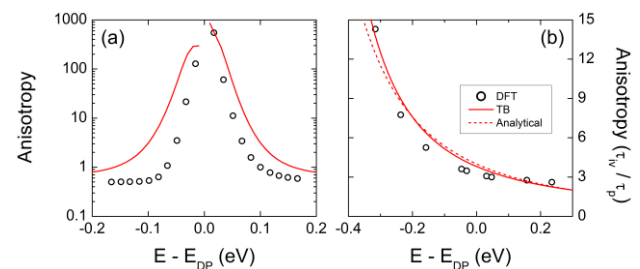
## References

- [1] M. Drögeler et al., Nano Lett. 16 (2016) 3533-3539
- [2] M. Gmitra et al., Phys. Rev. B 93 (2016) 155104
- [3] Z. Wang et al., Nat. Commun. 6 (2015) 8339
- [4] K.-H. Jin and S.-H. Jhi, Phys. Rev. B 87 (2013) 075442
- [5] P. Lee et al., ACS Nano 9 (2015) 10861-10866
- [6] K. Song et al., Nano Lett., submitted

## Figures



**Figure 1:** Simulated graphene/TI systems. (a) A highly commensurate unit cell and (b) a larger unit cell that samples a variety of atomic configurations. (c) A side view of the simulated system.



**Figure 2:** Giant spin lifetime anisotropy induced in the graphene layer by the TI, for (a) the commensurate unit cell in Fig. 1(a), and (b) the larger unit cell in Fig. 1(b).